

## Light Emitting Diode(InGaAlP)

**KODENSHI**

## KLB-16AR

KLB-16AR has a high bright InGaAlP Red LED and has the optimized optical characteristics.

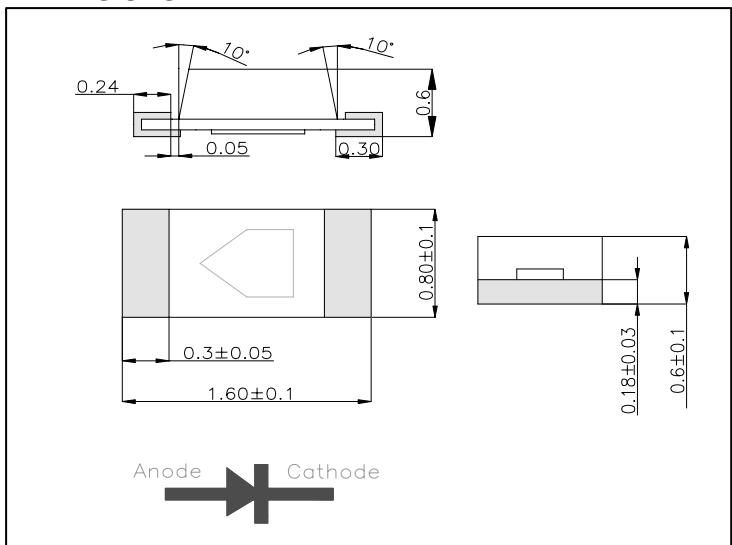
### Features

- Ultra Wide Viewing Angle
- Very Thin Small SMD Package

### Applications

- Display
- Indicator
- Key Pad Back Light

### DIMENSIONS



### Maximum Ratings

[ Ta=25°C ]

Parameter	Symbol	Ratings	Unit
Reverse Voltage	V <sub>R</sub>	5	V
Forward current	I <sub>F</sub>	25	mA
Pulse forward current <sup>*1</sup>	I <sub>FP</sub>	60	mA
Power dissipation	P <sub>D</sub>	70	mW
Operating temperature	T <sub>opr.</sub>	-30 ~ +85	°C
Storage temperature	T <sub>stg.</sub>	-40 ~ +105	°C
Soldering Temperature <sup>*2</sup>	T <sub>sol.</sub>	260	°C

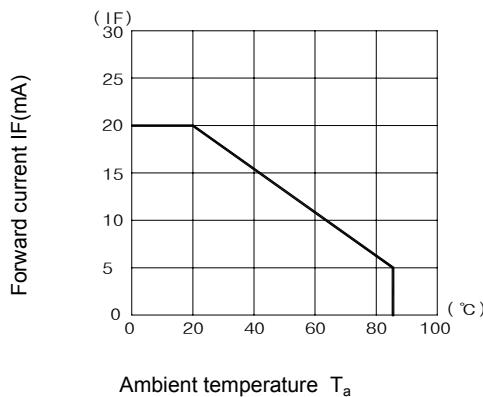
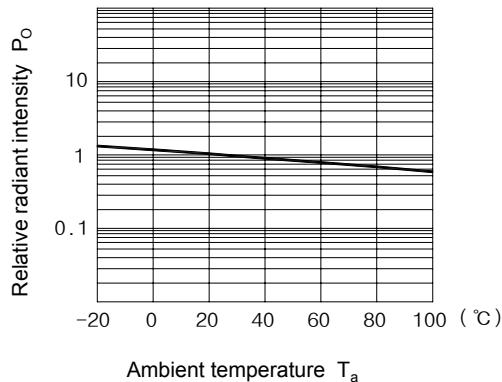
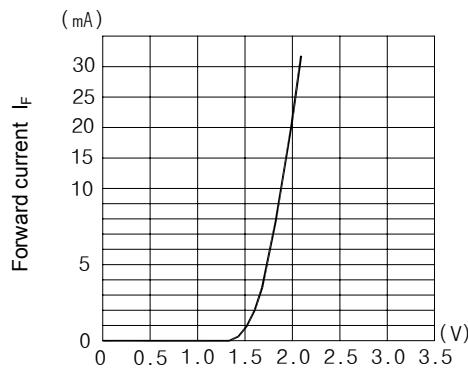
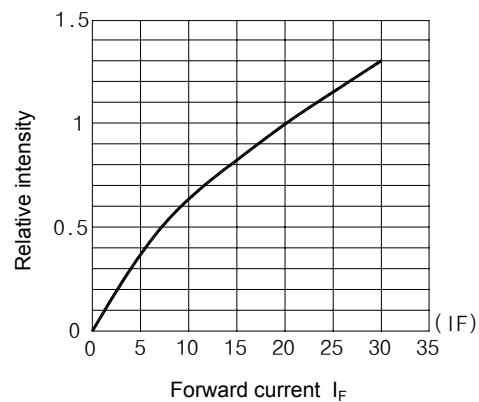
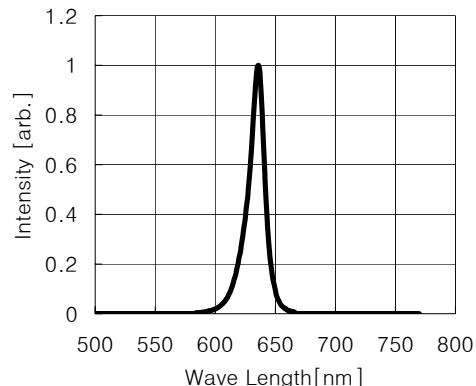
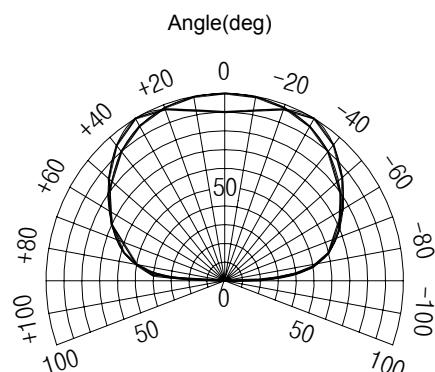
\*1. I<sub>FP</sub> Measured under duty ≤ 1/10 @ 1KHz

\*2. Soldering time ≤ 5 Sec

### Electro-Optical Characteristics

[ Ta=25°C ]

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	-	2.0	2.2	V
Luminous Intensity	I <sub>V</sub>	I <sub>F</sub> = 10 mA	15	25	-	mcd
Doninant Wave Length	λd	I <sub>F</sub> = 10 mA	620	-	630	nm
Spectral half bandwidth	Δλ	I <sub>F</sub> = 10 mA	-	20	-	nm
Half angle	Δθ	I <sub>F</sub> = 10 mA	-	160	-	deg.

**Forward current vs.  
Ambient temperature****Relative radiant intensity vs.  
Ambient temperature****Forward current vs.  
Forward voltage**Forward voltage  $V_F$ **Radiant Intensity vs.  
Forward current****Relative intensity vs.  
Wavelength****Radiant Pattern**

Relative intensity(%)